

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Priority Application Serial No. 10/340,126
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Inventor Zhongze Wang
Assignee Micron Technology, Inc.
Priority Group Art Unit 2812
Priority Examiner Jennifer M. Kennedy
Attorney's Docket No. MI22-2343
Title: Method of Forming Silicon-on-Insulator Comprising Integrated
Circuitry (as Amended)

PRELIMINARY AMENDMENT

To: Mail Stop Patent Application
Commissioner for Patents
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Alexandria, VA 22313-1450

VIA EXPRESS MAIL

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Please enter the following amendments prior to examining the above-identified application.

AMENDMENTSAmendments to the Title

Please change the title to the following: --METHOD OF FORMING
SILICON-ON-INSULATOR COMPRISING INTEGRATED CIRCUITRY--.